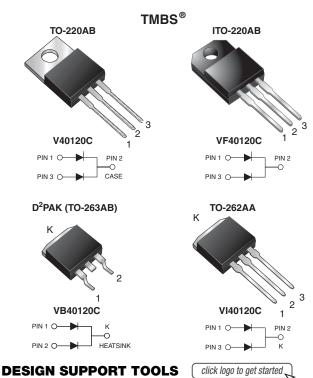


Vishay General Semiconductor

### **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.43 \text{ V}$  at  $I_F = 5 \text{ A}$ 



### 3D



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 20 A					
V <sub>RRM</sub>	120 V					
I <sub>FSM</sub>	250 A					
V <sub>F</sub> at I <sub>F</sub> = 20 A	0.63 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

#### **FEATURES**

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

(e3)

• High efficiency operation

TO-262AA package)

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

• Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and

 Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V40120C	VF40120C	VB40120C	VI40120C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	V <sub>RRM</sub> 120			V		
Maximum average forward rectified current (fig. 1)	per device		40				А	
	per diode	I <sub>F(AV)</sub>	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	250			Α		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 100 mH per diode		E <sub>AS</sub>	180				mJ	
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode		I <sub>RRM</sub>	I <sub>RRM</sub> 0.5			Α		
Voltage rate of change (rated V <sub>R</sub> )			10 000			V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150			°C		



# V40120C, VF40120C, VB40120C, VI40120C

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	120 (minimum)	-	V	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.50	-	V	
	I <sub>F</sub> = 10 A			0.60	-		
	I <sub>F</sub> = 20 A			0.78	0.88		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.43	-		
	I <sub>F</sub> = 10 A			0.53	-		
	I <sub>F</sub> = 20 A			0.63	0.71		
Reverse current per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	19	-	μΑ	
		T <sub>A</sub> = 125 °C		10	-	mA	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		-	500	μΑ	
		T <sub>A</sub> = 125 °C		22	45	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V40120C	VF40120C	VB40120C	VI40120C	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	1.8	4.0	1.8	1.8	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40120C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF40120C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VB40120C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40120C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40120C-E3/4W	1.46	4W	50/tube	Tube			
TO-220AB	V40120C-M3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF40120C-M3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VB40120C-M3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40120C-M3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI40120C-M3/4W	1.46	4W	50/tube	Tube			



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#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

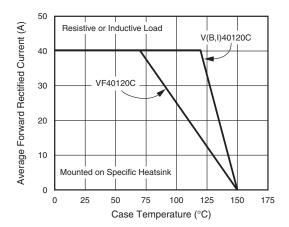


Fig. 1 - Maximum Forward Current Derating Curve

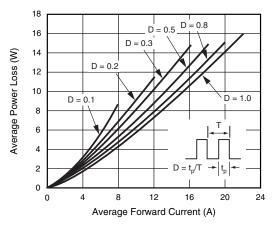


Fig. 2 - Forward Power Loss Characteristics Per Diode

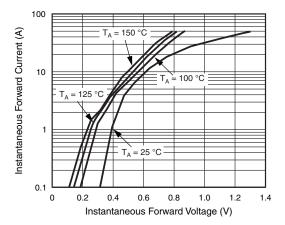


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

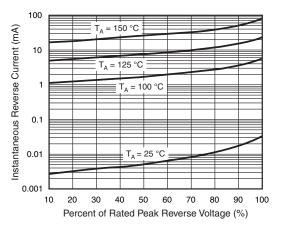


Fig. 4 - Typical Reverse Characteristics Per Diode

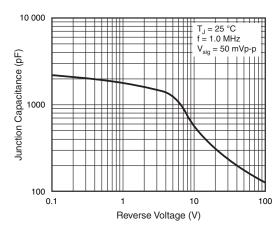


Fig. 5 - Typical Junction Capacitance Per Diode

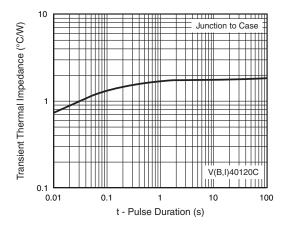


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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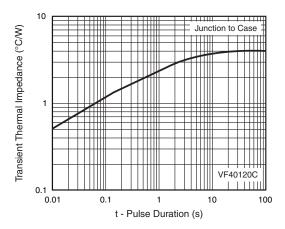
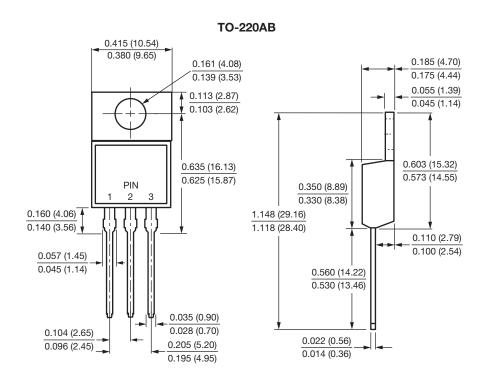


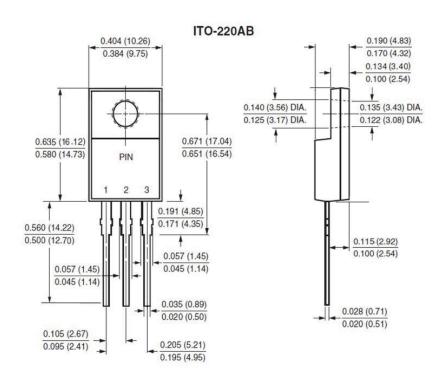
Fig. 7 - Typical Transient Thermal Impedance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

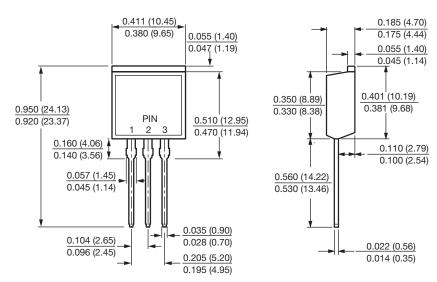




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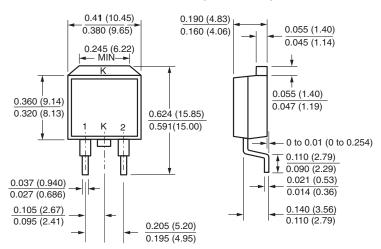
#### TO-262AA



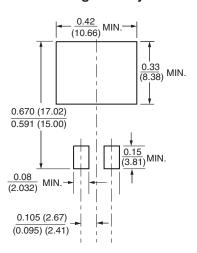
# V40120C, VF40120C, VB40120C, VI40120C

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#### D<sup>2</sup>PAK (TO-263AB)



#### **Mounting Pad Layout**





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